

UTC UNISONIC TECHNOLOGIES CO., LTD

UTG50N120FQ-G2

Preliminary

Insulated Gate Bipolar Transistor

1200V TRENCH GATE **FIELD-STOP IGBT**

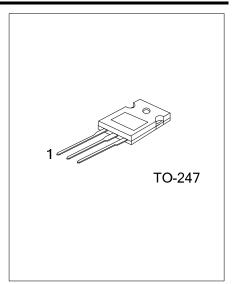
DESCRIPTION

The UTC UTG50N120FQ-G2 is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

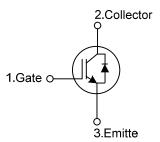
The UTC UTG50N120FQ-G2 is suitable for the resonant or soft switching applications.

FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: VCE(SAT).Typ.= 1.77V @ Ic=50A, VGE=15V (Tc =25°C)



SYMBOL



ORDERING INFORMATION

Ordering Number			Deelvere	Pin Assignment			Deeking
Lead Free Halogen Free		Package	1	2	3	Packing	
UTG50N120FQL-G2-T47-T	UTG50N120FQG	G-G2-T47-T	TO-247	G	С	ш	Tube
Note: Pin Assignment: G: Gate C: Collector E: Emitter							
UTG50N120EOG-G2-T47	7 -						

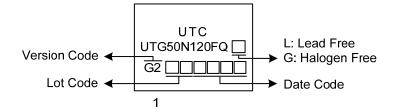
UTG50N120FQG-G2-T47-T		
TTT-	(1)Packing Type	(1) T: Tube
	(2)Package Type	(2) T47: TO-247
	(3)Version Code	(3) Version G2
	(4)Green Package	(4) G: Halogen Free and Lead Free, L: Lead Free

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MARKING





PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage		V _{CES}	1200	V
Gate-Emitter Voltage		N/	±20	V
Transient Gate-emitter voltage (<i>t</i> p < 5	ms)	V _{GES}	±25	V
Continuous Colloctor Current	T _C =25°C		100	А
Continuous Collector Current	T _C =100°C	I _C	50	А
Collector Current Pulsed (Note 1)		I _{CM}	200	А
Diode Forward Current	T _C =25°C	IF	60	А
	T _C =100°C		30	А
Short Circuit Withstand Time V _{GE} = 15V, V _{CC} ≤ 200V		tsc		μs
Time between short circuits: ≥1.0s				
$T_{\rm VJ}$ = 25°C				
Power Dissipation (T _c =25°C)			PD	285
Operating Junction Temperature		TJ	-40 ~ +150	°C
Storage Temperature Range		T _{STG}	-55 ~ +150	°C

■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

 Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.
2. Pulse width limited by maximum junction temperature.

THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θις	0.44	°C/W



	ELECTRICAL	CHARACTERISTICS	(T _c =25°C, unless otherwise specified)
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PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Off Characteristics						
Collector-Emitter Breakdown Voltage	BV _{CES}		1200			V
Collector Cut-Off Current	ICES	V _{CE} =1200V, V _{GE} =0V			250	μA
G-E Leakage Current	I _{GES}	$V_{CE}=0V, V_{GE}=\pm 20V$			±250	nA
On Characteristics						
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}	4.5		6.5	V
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =50A, V _{GE} =15V T _C =25°C T _C =125°C		1.77 2.1	2.3	V V
Dynamic Characteristics				2.1		v
Input Capacitance	CIES		1	2600		pF
Output Capacitance	COES	V _{CE} =25V, V _{GE} =0V, f=1MHz		108		pF
Reverse Transfer Capacitance	C _{RES}			71		pF
Switching Characteristics						
Total Gate Charge	Q _G			198		nC
Gate-Emitter Charge	Q _{GE}	V _{CE} =600V, I _C =50A, V _{GE} =15V		19.7		nC
Gate-Collector Charge	Q _{GC}			120.4		nC
Turn-On Delay Time	t _{DON)}			18.4		ns
Rise Time	t _R			34.9		ns
Turn-Off Delay Time	t _{DOFF)}	V _{CC} =600V, I _C =50A, R _G =5Ω,		261		ns
Fall Time	t⊨	V _{GE} =0~15V, L=500µH		216.7		ns
Turn-On Switching Loss	Eon			3.749		mJ
Turn-Off Switching Loss	EOFF			4.64		mJ
SOURCE- DRAIN DIODE RATINGS AN	D CHARACTE	ERISTICS				
Forward Voltage Drop	VF	I⊧=50A			3.5	V
Reverse Recovery Time	trr		/	61.2		ns
Reverse Recovery Charge	Qrr	I⊧=50A, dI/dt=100A/µS, V _{CC} =400\	/	1480		nC



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